



Capacitor Discharging through Asynchronous Circuit Switching

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ASYNC'13: Santa Monica, May 20, 2013



Outline

- **Context**: Energy harvesting systems
- Origin of the problem: Reference-free voltage sensor, Analysis Issue
- Capacitor and Ring Oscillator: dynamic switching process
- **Circuit Model**: Charge equilibrium and switching index
- Solutions for super-threshold and sub-threshold regions
- Discussion can we extend this method to a more general characterisation of "energetic effort"?
- Conclusion

Energy harvesting systems



Sporadic source of energy does not allow for fancy power processing and therefore large storage.



Energy harvesting system

Power adaptive system



Energy harvesting system

- Adaptation level
 - Cell level: e.g. single-rail vs dual-rail gates
 - Circuit level: e.g. clock/power gating, DVS and DFS (synchronous design)
 - System level
 - $_{\odot}$ Control of computation load to fit the power profile
 - Computationally feasible mathematical models are now available that capture energy storage discharge characteristics in sufficient detail to let designers develop an optimization strategy [1].

^{1.} R. Rao, S. Vrudhula, and D. N. Rakhmatov, "Battery modeling for energy aware system design," *Computer, vol. 36, pp. 77-87, 2003.*

Energy harvesting system design

- Aims and objectives
 - **1. well-characterised computational circuit blocks**, in terms of energy per action.
 - 2. refined methods for the online measurement and sensing of voltage/power/energy paths.
 - high resolution methods for controlling power (e.g. power gating, dynamic voltage scaling) and switching activity (dynamic frequency scaling, clock gating, concurrency control, task scheduling).
 - 4. flexible (in terms of different levels of abstraction, granularity and accuracy) methods of modelling power management and multi-parametric (power, energy per operation, latency, throughput) analysis of modes of energising (rationing of power and Vdd levels) the computational load.

Example: voltage sensor without a reference



Voltage Sensor



Capacitor discharging



Output count and energy consumption



Capacitor Discharging Through Asynchronous Circuit Switching

- This work examines the relationship between the switching behaviour of a self-timed digital circuit and the dynamic characteristic of the voltage on the capacitor while the circuit is powered by the capacitor.
 - For this purpose, a sample system is considered that consists of an initially charged capacitor which is discharged through the switching of a ring oscillator.
 - Closed-form expressions are obtained for the supply voltage of the ring oscillator over time as it operates.

Dynamic Switching



- We employ a simple ringoscillator to serve as a selftimed digital circuit load.
- It is due to the fact that ringoscillator can closely mimic the switching behaviour of many closed loop delayinsensitive asynchronous circuits.





Circuit Model: switching process



Solution for Super-threshold

A valid assumption: in super-threshold region we can assume that the propagation delay is inversely proportional to the voltage, so we have:

Switching index	V_N	$t_s = \frac{A}{V}$	Physical time (t)
0	K^{0}	$\frac{A}{K^{0}}$	$\frac{A}{K^0}$
1	K^1	$\frac{A}{K^{1}}$	$\frac{A}{K^0} + \frac{A}{K^1}$
2	K^{2}	$\frac{A}{K^2}$	$\frac{A}{K^0} + \frac{A}{K^1} + \frac{A}{K^2}$
n	K^{n}	$\frac{A}{K^n}$	$\sum_{i=0}^{n} \frac{A}{K^{i}}$

Solution for Super-threshold

$$V_N = \frac{A}{t(1-K) + AK}$$

Hyperbolic function of time



More accurate solution for Superthreshold

A general model of gate delay propagation [1] is used:

$$t_{p} = \begin{cases} t_{p1} = \frac{pc_{l}V}{(V - V_{TH})^{\alpha}} \\ t_{p2} = \frac{pc_{l}V}{\frac{V - V_{TH}}{N_{s}}} \\ I_{0}e^{\frac{V - V_{TH}}{N_{s}}} \end{cases}$$

1 0.9 for A=10-11 8.0 0.7 Normalaised VCC 0.6 0.5 0.4 0.3 simulation result for 5-stage inverters 0.2 0.1 0 0.0E+0 2.0E-8 4.0E-8 6.0E-8 8.0E-8 1.0E-7 physical time, t(s)

Assuming $\alpha = 1.3$

$$\int_{0}^{n} \frac{AK^{i}}{\left(K^{i} - V_{THN}\right)^{\alpha}} di = V_{THN} + \left(\frac{-\frac{10}{3}A}{\ln K \cdot (t - B \cdot A)}\right)^{3.33}, B = \frac{\frac{10}{3}}{\ln K \cdot (1 - V_{THN})^{0.3}}$$

[1] "Sub-threshold Design for Ultra Low Power Systems", Alice Wang, Benton H. Calhoun, Anantha P. Chandrakasan 18

Solution for Sub-threshold

Switching index	V_N	t _s	Physical time (<i>t</i>)
0	K^{0}	A	A
1	K^1	AKe ^{c(1-K)}	$A + AKe^{c(1-K)}$
2	K^2	$AK^2 e^{c(1-K^2)}$	$A + AKe^{c(1-K)} + AK^2e^{c(1-K^2)}$
n	K^n	$AK^{n}e^{c(1-K^{n})}$	$A\sum_{i=0}^{n} K^{i} e^{c(1-K^{i})}$

Solution for Sub-threshold

$$t = A_{0}^{n} K^{i} e^{C(1-K^{i})} di = -A \frac{e^{C(1-K^{i})}}{C \cdot \ln K} \Big|_{i=0}^{i=n}$$

$$V_{N} = 1 - \frac{\ln(1 - \frac{Ct \ln K}{A})}{C}$$

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$$V_{N}$$

Discussion

In a more complex circuit we have:



- In a complex circuit, the switching activity is not as uniform as a ring oscillator.
- However, the overall switching activity within a single charging period can still be simplified as a single exponent term.
- The expansion of these will generate a complex form of the hyperbola function.

Discussion (hypotheses!)

- The energy profile of a circuit is best predictable if the capacitor discharging characteristic of the circuit switching maintains the ideal hyperbola function.
- New system or circuit design objective:
 - A design methodology should provide the switching activity profile which guarantees such an ideal hyperbola function. In such a design, energetic effort across the system would need to be uniform.
 - Overall energy consumption of the circuit at the single switching time over the period of an operation is simple the energy effort.
 - Uniform energy effort makes the circuit energy profile predictable!

Conclusion

- We explored the relationship between a capacitor based power source and a switching circuit, i.e. the capacitor state as a function of time.
- The analysis was fulfilled over the two regions of operation, super and sub-threshold for simple ring oscillator. Leakage, short circuit effects were ignored here.
- It shows a hyperbolic character of the discharge process, determined by the intrinsic properties of the circuit captured by coefficients A and K
- This could be used as an approximation to characterise energy profile of digital (async) loads in energy harvesting systems

Future work

- Investigate the relationship between the hyperbolic discharge process and more general fractal dynamics calculus
- Investigate the idea of "energetic effort" and possibilities of optimising asynchronous circuits on the basis of uniformity in space and time (balanced effort)
- See potential for developing adaptive control laws for charging and discharging processes in energy harvesting systems and not only but in all energy and power constrained systems

